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Published in: Journal of the American Chemical Society

DOI: 10.1021/jacs.0c06508

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Document Version Publisher's PDF, also known as Version of record

Publication date: 2020

Link to publication in University of Groningen/UMCG research database

Citation for published version (APA): Kumar, S., Soni, S., Danowski, W., van Beek, C. L. F., Feringa, B. L., Rudolf, P., & Chiechi, R. C. (2020). Correlating the Influence of Disulfides in Monolayers across Photoelectron Spectroscopy Wettability and Tunneling Charge- Transport. *Journal of the American Chemical Society*, *142*(35), 15075-15083. https://doi.org/10.1021/jacs.0c06508

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Article

Correlating the Influence of Disulfides in Monolayers across Photoelectron Spectroscopy Wettability and Tunneling Charge-Transport

Sumit Kumar, Saurabh Soni, Wojciech Danowski, Carlijn L. F. van Beek, Ben L. Feringa, Petra Rudolf,* and Ryan C. Chiechi*



ABSTRACT: Despite their ubiquity, self-assembled monolayers (SAMs) of thiols on coinage metals are difficult to study and are still not completely understood, particularly with respect to the nature of thiol-metal bonding. Recent advances in molecular electronics have highlighted this deficiency due to the sensitivity of tunneling charge-transport to the subtle differences in the overall composition of SAMs and the chemistry of their attachment to surfaces. These advances have also challenged assumptions about the spontaneous formation of covalent thiol-metal bonds. This paper describes a series of experiments that correlate changes in the physical properties of SAMs to photoelectron spectroscopy to unambiguously assign binding energies of noncovalent interactions to physisorbed disulfides. These disulfides can be converted to covalent metal-thiolate bonds by exposure to free thiols, leading to the remarkable observation of the total loss and recovery of length-dependent

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IOURNAL OF THE AMERICAN CHEMICAL SOCIETY

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 $\mathbf{Pure SAM}$ $\mathbf{Pure SAM}$

tunneling charge-transport. The identification and assignment of physisorbed disulfides solve a long-standing mystery and reveal new, dynamic properties in SAMs of thiols.

INTRODUCTION

Organic monolayer films have found a wide variety of applications in the fields of chemistry, physics, molecular biology, biomedical engineering, and materials science,¹⁻³ including nanopatterning,^{4,5} molecular-scale devices,^{6,7} optical materials,^{8,9} biosurfaces,¹⁰ adhesion,¹¹ wettability,¹² and corrosion.¹³ Self-assembled monolayers (SAMs) of thiols on gold are a particularly versatile and well-studied class of organic monolayer films that leverage the two-dimensional (2D) selfassembly of organic molecules mediated by the strong, but reversible, binding of thiols to metal surfaces.^{14–19} The structural and interfacial properties of derivatives of alkanethiols in mixed monolayers were recently found to be closely related to the transport properties of tunneling junctions.²⁰⁻²⁶ The special nature of this type of bonding is what imparts SAMs with some of their most useful properties, because it governs the dynamics of self-assembly and allows for the formation of densely packed monolayers as well as selfrepair, in-place exchange, the formation of mixed monolayers, and responsiveness. Elucidating the special nature of covalent Au-S bonding on surfaces has, however, proven challenging. Studies of the stability of thiol-based SAMs under various conditions of SAM formation, such as pH,²⁷ solvent effect,² influence of the roughness²⁹ of Au substrates, photoirradiation,³⁰ effects of redox environments,³¹ etc., provide insight into the self-assembly process. Optical tweezers,

magnetic tweezers, and single-molecule force spectroscopy³² provide information about the properties of individual thiols bound to Au. It is, however, particularly challenging to investigate the nature of Au–S bonds in a SAM in a context in which it is useful, for example, on a macroscopic substrate under ambient conditions because they are, ultimately, self-assembled nanomaterials.²

The central challenge to studying large-area SAMs (as opposed to single-molecule or nanoscopic areas on Au single-crystals) is that they are heterogeneous and can comprise different types of Au–S bonds that affect the properties of the SAM. For example, thiolated-DNA physisorbed on Au as either Au···SH–R or Au···(S–S)···Au (where "–" represents a covalent bond, and "···" represents a noncovalent interaction; see Figure 1) resulted in SAMs with different properties than SAMs of the same thiolated-DNA comprising only covalent interactions.³³ Similarly, it has been shown that growing SAMs from solutions containing differing fractions of disulfides (S–S

 Received:
 June 16, 2020

 Published:
 August 10, 2020







Figure 1. Three modes by which d-DTT can bind to Au: bidentate-physisorbed ((bp)d-DTT), monodentate-physisorbed ((mp)d-DTT), and bidentate-chemisorbed ((bc)-DTT) where "–" and "…" represent covalent and noncovalent interactions, respectively, and d stands for a dimerized S–S bond.

bonds) alters the rectification ratio in large-area tunneling junctions.³⁴ Likewise, there is also evidence that disulfide and thiol molecules pack and orient differently on Au.³⁵ In the field of molecular electronics, which is sensitive to small perturbations in structure/bonding, the nature and influence of Au-S bond(s) at the electrode interface are still not well understood. In their pioneering work on SAMs of thiols, Nuzzo et al. observed that S-S bonds are reduced spontaneously on Au surfaces to form Au-S bonds, finding no evidence of residual S-S bonds.^{14,15} Subsequently, Whitesides et al. observed that thiols out-compete disulfides in the formation of SAMs and again did not observe any residual S-S bond.¹⁷ However, Venkataraman et al. observed that, in single-molecule junctions, covalent Au-S and noncovalent Au...(S-S)...Au/Au...SH-R bonds affect injection currents differently, from which they further concluded

that Au···(S–S)···Au and Au···SH–R interactions can coexist in SAMs formed from thiols.³⁶ In this paper, we reconcile the apparent discrepancies in the nature of gold–thiolate binding that have been revealed by molecular–electronic studies and overcome a long-standing challenge to spectroscopic studies on SAMs by unambiguously identifying and assigning Au···(S– S)···Au bonds using photoelectron spectroscopy and correlating their presence to transport properties in tunneling junctions comprising SAMs.

X-ray photoelectron spectroscopy (XPS) is a powerful tool for identifying chemical species in SAMs. It can provide information about Au-S interactions, characterize the average thicknesses of monolayers, elucidate the tilt angles of molecules with respect to the surface normal, and determine the orientation and vertical positions of functional groups. In short, XPS is a comprehensive spectroscopy for interrogating SAMs of thiolates.³⁷ In the S 2p core level of an XPS spectrum at binding energies of 161.8-162.0 eV, an S 2p_{3/2} peak corresponds to a Au-S covalent bond. Shifts in this range of binding energies correspond to changes in the oxidation state of the sulfur atom, reflecting changes in interactions between Au and S, whether they be covalent or noncovalent in nature. However, in several XPS and high-resolution (HR) XPS studies (at a resolution limit of 0.05 eV),^{33,35} Au...(S-S)...Au and Au…SH-R interactions have been interchangeably assigned to the same binding energies, ranging from 163 to 164 eV, e.g., a commonly occurring S $2p_{3/2}$ peak at (163.6 \pm 0.2) eV. $^{38-42}$ The ambiguity of this assignment limits XPS to a qualitative measure of the quality of a SAM; a high-quality SAM lacks a peak at (163.6 ± 0.2) eV because it can only be ascribed to noncovalent binding. The assignment



Figure 2. (a) Water contact angles on SAMs of pure DTT grown from d-DTT with immersion times of 20 min (20m), 120 min (120m), and 720 min (720m). Contact angles of SAM of pure ethanethiol (EtSH) serve as a reference. (b) Water contact angles (red) and normalized Au/S ratios from XPS (black) versus the immersion time for SAMs of DTT (squares) and EtSH (circles). (c) XPS spectra of the SAMs 20m, 120m, 720m. The left column shows the corresponding S 2p core-level spectra, which comprise multiple doublets corresponding to Au—S bonds (black curve), hollow-site bonds (purple curve), and S—S bonds (red curve). The right column shows the C 1s core-level spectra, which comprise peaks corresponding to C—C bonds (black curve), C—S/C—OH bonds (green curve), and C=O bonds (blue curve).



Figure 3. (a) Water contact angles on mixed monolayers of DTT grown from pure d-DTT SAM immersed in ethanolic solutions of EtSH for 0, 6, 18, and 24 h (exchange time). (b) Water contact angles (red) and Au/S ratios of integrated peak-areas normalized to SAMs of pure EtSH from XPS (black) versus exchange time for SAMs of DTT with EtSH. (c) XPS spectra of the substrates pictured in part a. The left column shows the S 2p core-level spectra, which comprise two doublets corresponding to Au—S bonds (black curve) and S—S bonds (red curve). The right column shows the C 1s core-level spectra comprising peaks corresponding to C—C bonds (black curve), C—S/C—OH bonds (green curve), and adventitious C=O species (blue curve).

of this peak to a specific chemical species enables quantitative measures of quality and deeper insight into the overall structure of a SAM and its interaction with the substrate upon which it self-assembles both pro- and retroactively.

For this study, we returned to dithiolreitol ((2S,3S)-1,4-bis(sulfanyl)butane-2,3-diol, DTT, see Figure 1) because it is well-established and readily forms stable, internal disulfide bonds. We grew SAMs of pure DTT and mixed monolayers of DTT and ethanethiol (EtSH)—which is effectively half of a DTT molecule—and varied the growth conditions while monitoring the S 2p core-level spectra. These data were further correlated to surface hydrophobicity and tunneling charge-transport through the thickness of the monolayers.

RESULTS AND DISCUSSION

Owing to the formation of a stable six-membered ring, DTT readily forms internal disulfide bonds to form d-DTT, which can then be used to study Au-S interactions in the absence of free thiols. As depicted in Figure 1, d-DTT molecules can bind to the surface of Au in different configurations. Figure 1a,b depicts two possible binding modes in which the internal disulfide bond is preserved, and all Au-S interactions are, therefore, noncovalent. These are denoted as bidentatephysisorbed d-DTT, (bp)d-DTT (both sulfur atoms are interacting with Au), and monodentate-physisorbed d-DTT, (mp)d-DTT (only one sulfur atom is interacting with Au). In the third possible configuration, Figure 1c, both sulfur atoms are covalently bound to Au, which is denoted bidentatechemisorbed DTT, (bc)-DTT. All of the SAMs of d-DTT on Au surfaces were prepared at room temperature from ethanolic solutions (0.1 mM) of d-DTT with varying immersion times, as explained below.

XPS and Contact Angle Measurement. To characterize the evolution of S/Au interactions, d-DTT SAMs were grown with different immersion times of 20, 120, and 720 min denoted as 20m, 120m, and 720m, respectively, as shown in Figure 2. The S 2p core-level spectra (shown in Figure 2c) comprise multiple doublets, confirming the presence of multiple oxidations states of S. The doublets peaked at 161.3, 162.0, and 163.6 eV correspond to S bound to Au hollow-sites (purple curve),43 covalent Au-S bond (black curve),^{40,41,43} and physisorbed disulfide (red curve),^{40,44,45} respectively. The peak at 161.3 eV (purple curve) that is present in the spectra of 20m is absent in the 120m and 720m samples, which suggests that SAMs of d-DTT form by first filling Au hollow-sites to form a disordered monolayer.⁴³ However, rather than evolving into a single S-Au interaction with time, hollow-site bonding is replaced by a mix of Au-S and S-S species as indicated by the persistent presence of both red and black curves in 120m and 720m. Thus, at least two of the three species shown in Figure 1 persist at longer immersion times.

We ascribe the peak at 163.6 eV (red curve) exclusively to (bp)d-DTT using the following reasoning: Sulfur is more electronegative than hydrogen, meaning that the sulfur peak of a physisorbed organic thiol will appear at a lower binding energy than the corresponding disulfide, specifically in the range 163.0–164.0 eV;^{33,35,46,47} thus, it cannot be physisorbed thiol. Moreover, d-DTT is a pure disulfide, meaning that the thiol protons would have to be provided by ethanol during the growth of the SAM. Formally, this is a redox reaction in which 2 equiv of H• are abstracted from ethanol to form the peroxide (CH₃CH₂O)₂ and DTT, which is unlikely. Finally, binding energies for physisorbed and free thiols have been reported at

163.2 eV.^{43,48} The absence of any such peaks near or below the peak at 163.6 eV supports our hypothesis that the red curve corresponds to a single sulfur species, specifically (bp)d-DTT (Figure 1a).

Further evidence that (mp)d-DTT is not present in the SAMs can be found in the carbon spectra. The C 1s core-level region comprises multiple singlets: 284.5 eV (black curve),⁴⁹ 286.5 eV (green curve),^{50–52} and 288.8 eV (blue curve),^{53–55} corresponding to C—C bonds, C—S/C—OH bonds, and adventitious C=O species, respectively. Although the number and relative intensities of the peaks do not change significantly with immersion time, the green peak shifts to a lower binding energy by 0.5 eV between 20m and 720m, indicating an increase in electron density around the carbon atoms. This increase could be due to the formal reduction of sulfur (from S—S to Au^{$\delta+-S^{\delta-}$}), back-bonding in (bp)d-DTT (i.e., Au...S), hydrogen bonding between the OH groups as order within the SAM increases, or any combination thereof.

The density of organic thiols/disulfides in a SAM can be determined from the ratios of the integrated peak-areas of Au and S; the ratio of Au/S decreases as more thiol/disulfide adsorbs. Figure 2b compares this ratio for d-DTT (black squares), normalized to a SAM of EtSH grown for 720 min, showing that, indeed, the density of the SAM increases with immersion time commensurate with a decrease in water contact angle from the increasing density (and order) of the OH groups at the ambient interface. The water contact angle reaches a minimum of $(40 \pm 3)^\circ$ for 720m, in agreement with the literature values.¹⁴ Thus, although the water contact angle indicates a densely packed SAM of DTT, the persistence of the two doublets (black and red curves in Figure 2c) in the S 2p core-level region indicates that SAMs grown from d-DTT comprise a mixed phase of two distinct Au–S interactions.

For further insight into the nature of the two Au-S interactions, we prepared mixed monolayers of d-DTT and EtSH by exposing pure SAMs of DTT (120m) grown from d-DTT to 0.1 mM ethanolic solutions of EtSH for varying times. The data in Figure 3 are labeled with these exposure times (i.e., without varying the initial 120m used to form the starting pure SAM of DTT). The S 2p core-level region (which is identical to Figure 2b 120m) comprises two doublets at 161.8 eV⁴⁰ (black curve) and 163.6 eV (red curve) labeled as the Au-S and S-S bond. The relative amounts of S-S, calculated from the area under the red curve relative to the total S 2p core-level spectra, are $(37 \pm 2)\%$, $(25 \pm 3)\%$, $(8 \pm 2)\%$, and 0% for exchange times of 0, 6, 18, and 24 h, respectively. The overall trend shows a decrease in S-S with exchange time, eventually disappearing completely at 24 h. This trend indicates either that DTT is replaced completely by ethanethiol, or the S-S bond is reduced at the surface by exposure to ethanethiol, or a mixture of both. In any case, the commensurate reduction in the peak at 163.6 eV supports our hypothesis that this binding energy uniquely results from the presence of S-S bonds in the SAM.

The C 1s core-level spectra in Figure 3 comprise three different singlets corresponding (as in the pure SAMs of DTT in Figure 2) to C—C (black curve), C—S/C—OH (green curve), and adventitious C=O (blue curve). Interestingly, the peak of the green curve again shifts to lower binding energy by 0.5 eV between 0 and 6 h and then remains unchanged for rest of the samples. As with the pure SAMs, this shift reflects an increase in electron density on the carbon atoms and could be due to increasing hydrogen bonding at the ambient interface

and/or the formal reduction of sulfur. In addition, these SAMs are exposed to EtSH for increasing periods of time, which is reflected by the reduction in the relative amount of C-S/C-OH (in C 1s core-level spectra), sharply from 0 to 6 h, and then only slightly from 6 to 24 h. Thus, after pure SAMs of DTT are exposed to EtSH for 24 h, only one sulfur species (Au-S) is present in the XPS spectrum; however, the carbon spectra still show 36% of C-S/C-OH, indicating that DTT is still present.

Figure 3b shows the integrated peak-area ratios of Au/S (normalized to pure SAMs of EtSH) and water contact angles as a function of time exposed to EtSH. These data show that the exchange process can be divided into three different zones. In Zone-1 (0-6 h), the decreasing Au/S ratio and increasing contact angle suggest the replacement of weakly bound d-DTT by EtSH, decreasing the density of OH groups at the ambient interface. As described above, SAMs of DTT prepared by short immersion times (120m or 0 h sample) in solutions of d-DTT contain myriad defects and are disordered due to weakly bound d-DTT. Thus, after 6 h of exchange, EtSH fills the defects and displaces weakly bound d-DTT from the surface. In Zone-2 (6-8 h), the Au/S ratio increases slightly, while the water contact angle remains almost unchanged. This trend indicates that the amount of S (atoms) is nearly constant if not decreasing slightly, and the ratio of DTT:EtSH in the SAM remains constant. The XPS spectra (Figure 3c, red curve), however, indicate that the amount of S-S decreases by approximately 17% while the amount of C-S/C-OH remains constant. Together, these data suggest that over the 6-18 h time interval (Zone-2), the exchange process is dominated by the rearrangement of Au-S bonds on the surface. Over the same time interval, S-S bonds are cleaved at the surface, presumably reducing them to form covalent Au-S bonds. In Zone-3 (18-24 h), the Au/S increases sharply, and the water contact angle increases, indicating the desorption of DTT, presumably because it is displaced by EtSH. Over the same 18-24 h time interval, the S 2p core-level spectra show the complete loss of S–S, resulting in a single Au–S species in the mixed monolayer, but not complete replacement by EtSH, as substantial C-O/C-S peaks remain.

The O 1s spectrum (Figure S13a) confirms the presence of C-OH species at the ambient interface of all of the mixed SAMs, while there is no trace of C-OH in the spectra of SAMs of pure EtSH, which are shown in the bottom row of Figure S13b. The O 1s spectrum of mixed monolayers of DTT obtained after 6 h of exposure to EtSH is shifted to lower binding energies by 0.3 eV, consistent with the shift observed in the C 1s spectrum (Figure S12c). The variation of the O 1s (Figure S12a) spectral intensity with exchange time (0-24 h)further supports our assertions with respect to the relative amounts of C-S/C-OH species determined from the C 1s spectra (Figure S12c). Taken together, the data suggest that the disappearance of the peak at 163.6 eV occurs by different mechanisms. Exposure to EtSH results in the evolution of the peak at 162.0 eV in the S 2p core-level spectra; during these processes, the contact angle and Au:S ratio (Zone-3) clearly show the formal reduction of physisorbed S–S to chemisorbed Au-S, and we can unambiguously ascribe the peak at 163.6 eV in the core-level S 2p spectra to physisorbed S–S. The S 2ppeaks of (mp)d-DTT and (bp)d-DTT are indistinguishable on the surface of Au only because of the resolution limit of XPS, but that does not preclude the assignment of the peak at 163.6 eV to S-S present on the surface of Au. Although we



Figure 4. (a) Semilog plots of current density versus voltage (J-V) of SAMs of pure **C0**, **C1**, **C5**, and **C9** molecules on Au^{TS} measured with an EGaIn tip (the R groups and commensurate molecular lengths are defined in Table 1). (b) Values of β at different applied bias computed from the J-V curves in panel a according to eq 1 showing no dependence on the length of the R group. (c) Semilog J-V curves of the same series as panel a in mixed monolayers with octanethiol. (d) Value of β at different applied biases computed from the J-V curves in panel c showing a clear dependence on the identity of the R group.

lack sufficient spectroscopic insight to prove the mechanism of disulfide–thiolate interconversion, Figure S11 presents a surface-analogue of disulfide metathesis in which EtSH converts S–S to Au–S, producing $CH_3CH_2S_2$ to balance the stoichiometry. Such metathesis is well-known in solution.⁵⁶

Tunneling Charge-transport Characterization. The tunneling charge-transport properties of SAM simple organic thiols (e.g., aliphatic molecules) are sufficiently well-characterized that the injection current density J_0 , tunneling decay coefficient β (from plots of log *J* vs molecular length according to eq 1, where d is the width of the tunneling barrier), and conductance can be used to evaluate their properties.⁵⁷ For example, differences in the conductance of mono- and dithiol and disulfide moieties can be used to ascertain whether molecules are physisorbed or chemisorbed on Au.³⁶ We employed a similar strategy, using a series of esters derived from $(\pm)\alpha$ -lipoic acid in which the thickness of the SAMs anchored identically to DTT can be varied. These compounds are labeled as C0 for the parent acid and C1, C5, and C9 for the methyl, pentyl, and nonyl esters, respectively, as shown in the inset of Figure 4a; e.g., $R = CH_3$ for C1. Table 1 summarizes the R groups and their theoretical length and the

Table 1. R Groups of the Cn Series Shown in Figure 4a and Corresponding Molecular Lengths Calculated Using DFT and Measured in SAMs by XPS

abbreviation (Cn)	R group	calculated molecular length (Å)	XPS pure SAM thickness (Å)
C0	Н	7.91	7.0 ± 0.7
C1	CH_3	9.25	8.0 ± 0.7
C5	C5H11	13.97	9.0 ± 0.8
С9	C9H19	18.90	16.0 ± 1.0

thicknesses of SAMs of their respective Cn lipoic acid derivatives as determined by density functional theory (DFT) calculations and XPS.

$$J = J_0 e^{-\beta d} \tag{1}$$

Figure 4 summarizes the tunneling charge-transport properties of SAMs of the lipoic acid derivatives and the corresponding mixed monolayers with octanethiol on template-stripped Au (Au^{TS}) substrates⁵⁸ using eutectic Ga– In (EGaIn) top-contacts.⁵⁹ In ordered, densely packed SAMs, the expectation is that the magnitude of J will vary exponentially with molecular length according to the Simmons model (eq 1, eqs S2, S3, and S5)⁶⁰ for SAMs of nalkanethiolates on Au $\beta \approx 0.75$ Å⁻¹ and does not depend strongly on applied bias.⁶¹ Although the lipoic acid series contains either a terminal carboxylic acid or internal ester, neither has a significant impact on β ; ^{62,63} however, Figure 4a,b shows almost no length-dependence, with $\beta = 0.01 \text{ Å}^{-1}$ and an approximately linear dependence on applied bias despite the very good agreement between the theoretical molecular length and experimental thicknesses of the SAMs (Table 1). The same data are shown in Figure 4c,d for mixed monolayers prepared by exposing pure SAMs of the lipoic acid derivatives (Cn) to octanethiol. The mixed monolayers show a clear length-dependence and $\beta = 0.53$ Å⁻¹. Since the length of octanethiol is invariant, this value of β reflects the changing width of a tunneling barrier imposed by the R groups in the Cnseries. This is in agreement with the work by Yoon et al. showing the reduction of defect-induced conductance in mixed SAMs compared to pure SAMs.²³ In both the pure and mixed monolayers (Figure 4c,d), we observe rectification in J-Vcurves, most significantly for C9 SAMs, which indicates that this is a molecular property, consistent with observations by Whitesides et al.^{64,6}

The S 2p core-level spectra (Figure 5) of SAMs of pure C1 exhibit two main doublets at 163.6 and 161.8 eV,



Figure 5. Representative XPS spectra of SAMs of pure C1 (top) and mixed monolayers of C1 and octanethiol (bottom). The left column shows the respective S 2p core-level spectra and fits revealing two doublets corresponding to Au—S (black) and S—S (red). The right column shows the respective C 1s core-level spectra and fits of the data revealing peaks ascribed to C—C (black), C—S/C—O (green), and O—C=O/C=O species (blue).

corresponding to S-S (40%) and Au-S (60%). In contrast, the mixed monolayers of C1 and octanethiol exhibit only one doublet at 161.8 eV, which is indicative of Au-S. The C 1s spectra are (qualitatively) unchanged in both mixed monolayers and pure SAMs. We chose octanethiol to form the mixed monolayers because it is slightly shorter than the molecular length of extended C0, which is a strategy that we have employed previously to ensure that the "background SAM" (octanethiol) does not directly contribute to the tunneling Article

barrier. 40,66,67 The recovery of the length-dependence of the tunneling currents is accompanied by the disappearance of the peak at 163.6 eV (labeled S-S in Figure 5). Jiang et al. demonstrated that even a relative intensity of 10% of a peak at 163.6 eV can alter the rectification ratio of tunneling junctions comprising ferrocene-terminated SAMs.⁶⁸ They ascribed the peak (correctly) to S-S and reasoned that the presence of disulfides in the SAM increases the leakage current, which reduces the rectification ratio. In our study, the relative intensity of the peak at 163.6 eV is 40% in pure SAMs of C1, which is significant enough to reduce β to near-zero. It also reduces the yield of working junctions to 30% (compared to 70% for the mixed monolayers), which implies a morphological effect as well, but our results support the hypothesis that the magnitude of a peak at 163.6 eV correlates to a contribution of nontunneling (leakage) current. However, eq 1 clearly shows that, whatever the morphological effects, they do not affect the thickness of the SAMs vis-à-vis the length of the R group. As we established above, exposure to octanethiol reduces S-S to Au–S; thus, we conclude that the peak at 163.6 eV is the result of physisorbed S-S, and that difference between that and chemisorbed Au-S is sufficient not just to affect β but also to mask the length-dependence entirely.

CONCLUSIONS

The presence of a peak at (163.6 \pm 0.2) eV in the S $2p_{3/2}$ region of XPS spectra of SAMs grown from thiols is generally associated with SAMs of poor quality. Its presence is correlated to subtle changes in the physical properties of SAMs, including their behavior in tunneling junctions. However, it has not previously been assigned to a single, well-defined chemical species. We have shown, experimentally, that it results from the presence of physisorbed S–S species and that these species can be reduced to Au-S by exposure to an *n*-alkanethiol which, over the course of 24 h, eliminates S-S and reorganizes the SAM without replacing it. Our results also provide valuable insight into the role of disulfides in tunneling junctions comprising SAMs and reveal the surprising result that the chemical coupling of a SAM to the bottom electrode (and any associated conformational changes) can affect the lengthdependence of tunneling currents to such an extent that the presence of disulfides can eliminate length-dependence entirely. While further study is needed to elucidate the exact nature of physisorbed S-S interactions, the assignment of the peaks at (163.6 ± 0.2) eV will aid these studies. The ubiquity of SAMs of thiols in science and engineering reflects their utility and versatility, and yet the nature of the chemical bonding between thiols and metal surfaces remains a source of controversy and a topic of research. The unambiguous elucidation of the chemical nature of the species that gives rise to the characteristic peak at (163.6 ± 0.2) eV enables further studies into the self-assembly process and the development of a more complete description of SAMs of thiols. The benefits of these insights are potentially as farreaching as the impact of SAMs themselves.

EXPERIMENTAL SECTION

Patterned Gold Electrode (Au^{TS}). The 100 nm thick Au (99.99% pure, Schöne Edelmetaal B.V.) was thermally deposited (0.5-2 Å/s) onto a 3.5 in silicon wafer (purchased from ePAK). For template stripping, glass substrates were cleaned with soap (Multi Purpose Detergent, Teepol), acetone, and ethanol in an ultrasonic bath for 10 min. Once the substrates were dried with a N₂ gun, we

deposited a droplet of UV adhesive (Norland Optical Adhesive 61) on the glass substrate. Those were then placed on the metal surface, and the entire wafer was cured with UV light for 300 s (50% intensity, IntelliRay 600) to activate the adhesive.

SAM Preparation and Treatments. SAMs of DTT were prepared by immersing a freshly stripped Au^{TS} substrate in a 1 mM solution of DTT in degassed, absolute ethanol (Macron Fine Chemicals) under Ar conditions, which was left for the specified incubation time in dark conditions. For J-V and XPS measurements, pure SAMs of the derivatives of $(\pm)\alpha$ -lipoic acid (CO-C9) were prepared from a 0.1 mM ethanolic solution of the respective molecules for 12 h. Mixed SAMs were prepared in two steps, where first, Au^{TS} substrates were immersed in a 0.1 mM ethanolic solution for 120 min of the respective molecules, and then, second, these pure SAMs were immersed in 1 mM ethanolic solution of octanethiol for 24 h at room temperature. All these samples were then washed three times in 3 mL of ethanol and blown dry with Ar gas.

EGaIn//**SAM**/**Au**^{TS} **Measurements.** The J-V traces were collected using a setup (described elsewhere⁶⁹) placed inside a flowbox (N₂ atm of <5% relative humidity and O₂ 1–3%) using LabView (National Instruments) with 5 sweeping cycles between +1 V and -1 V using a subfemtoamperometer (6430 SourceMeter, Keithley) and were analyzed using the GaussFit package.

XPS Analysis. XPS was performed using a Surface Science SSX-100 ESCA instrument, using monochromatic Al K α as the X-ray source ($h\nu = 1486.6$ eV). The pressure inside the measurement chamber was maintained below 10^{-9} mbar. The electron takeoff angle with respect to the surface normal was 37° . The diameter of the analyzed area was $1000 \ \mu$ m; the energy resolution was set to 1.1 eV to minimize data acquisition times. XPS spectra were analyzed with the fitting program Winspec (from LISE laboratory of the Facultés Universitaires Notre-Dame de la Paix, Namur, Belgium).

Computational Methodologies. To calculate the molecular lengths, geometry optimizations were performed using the Orca 4.0.1 software package.^{70,71} We used the B3LYP functional in combination with the default def2-SVP basis sets, and the lengths of the optimized geometry of the **C***n* molecules were measured using the distance between the terminal C/O atom of the alkyl chain and the sulfur atom next to the carbon atom to which the alkyl tail is attached.

ASSOCIATED CONTENT

③ Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/jacs.0c06508.

Synthetic detail and full characterization data for all new compounds, description of measurement techniques, and additional spectroscopic data on monolayers (PDF)

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Notes

The authors declare no competing financial interest.

ACKNOWLEDGMENTS

R.C.C. and S.K. acknowledge the European Research Council for the ERC Starting Grant 335473 (MOLECSYNCON). S.S. acknowledges the Zernike Institute for Advanced Materials. We thank the Center for Information Technology of the University of Groningen for their support and for providing access to the Peregrine high-performance computing cluster.

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